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### POWER MANAGEMENT

#### Features

- Power System:
  - Input voltage — 3V to 28V
  - Internal or external bias voltage — 3V to 5V
  - Integrated bootstrap switch
  - Programmable LDO output — 200mA
  - 1% reference tolerance -40 to +85 °C
  - EcoSpeed™ architecture with pseudo-fixed frequency adaptive on-time control
- Logic Input/Output Control:
  - Independent control EN for LDO and switcher
  - Programmable  $V_{IN}$  UVLO threshold
  - Power good output
  - Selectable ultrasonic power save mode
  - Programmable soft start time
- Protections:
  - Over-voltage and under-voltage
  - TC compensated  $R_{DS(ON)}$  sensed current limit
  - Thermal shutdown
- Any ESR — SP, POSCAP, OSCON, and ceramic capacitors
- Package:
  - Lead-free package — 5x5mm, 32-pin MLPQ
  - Fully RoHS/WEEE compliant and halogen free

#### Applications

- Office automation and computing
- Networking and telecommunication equipment
- Point of load power supplies and module replacement

#### Description

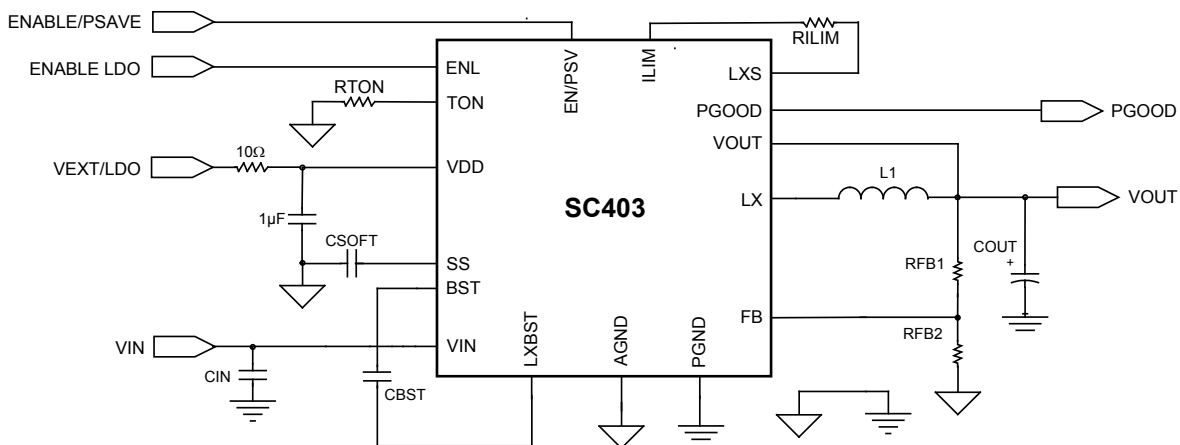
The SC403 is a stand-alone synchronous EcoSpeed™ buck power supply which incorporates Semtech's advanced patent-pending adaptive on-time control architecture to provide excellent light-load efficiency and fast transient response. It features integrated power MOSFETs, a bootstrap switch, and a programmable LDO in a 5x5mm package. The device is highly efficient and uses minimal PCB area.

The SC403 supports using standard capacitor types such as electrolytic or special polymer, in addition to ceramic, at switching frequencies up to 1MHz. The programmable frequency, synchronous operation, and selectable power-save provide high efficiency operation over a wide load range.

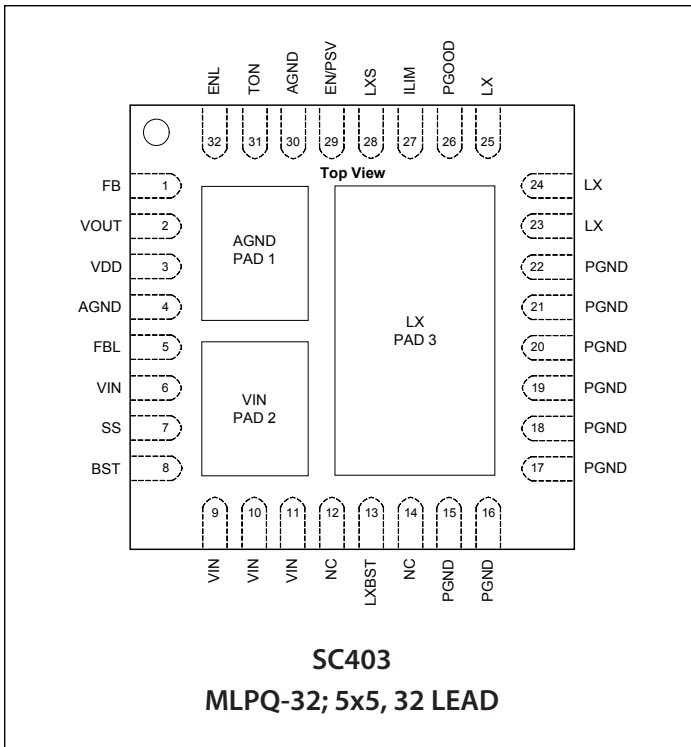
Additional features include a programmable soft-start, programmable cycle-by-cycle over-current limit protection, under and over-voltage protections, soft shutdown, and selectable power-save. The device also provides separate enable inputs for the PWM controller and LDO as well as a power good output for the PWM controller.

The wide input and bias voltage ranges, programmable frequency, and programmable LDO make the device extremely flexible and easy to use in a broad range of applications. The SC403 can be used in server computers and single cell or multi-cell battery systems in addition to traditional DC power supply applications.

#### Typical Application Circuit



### Pin Configuration



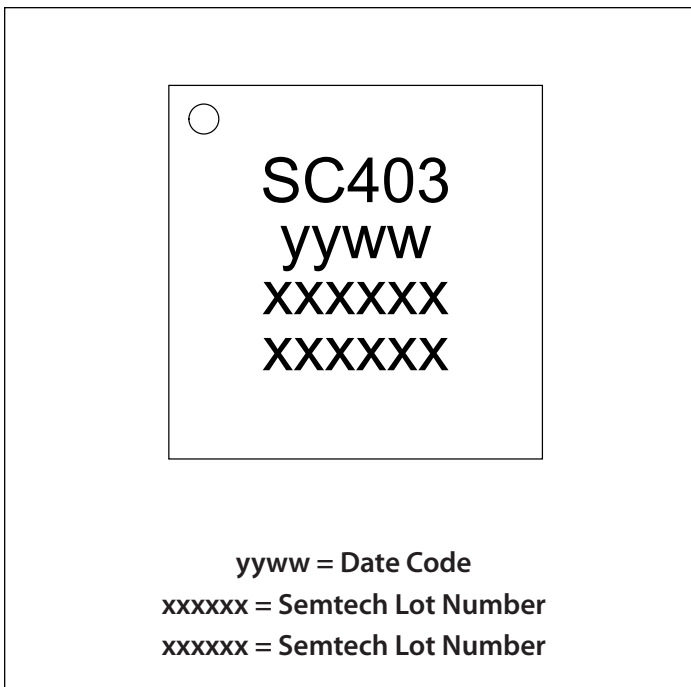
### Ordering Information

Device	Package
SC403MLTRT <sup>(1)(2)</sup>	MLPQ-32 5X5
SC403EVB	Evaluation Board

Notes:

- 1) Available in tape and reel only. A reel contains 3000 devices.
- 2) Lead-free package only. Device is RoHS/WEEE compliant and halogen free.

### Marking Information



## Absolute Maximum Ratings

LX to PGND (V).....	-0.3 to +30
LX to PGND (V) (transient — 100ns max.) .....	-2 to +30
VIN to PGND (V).....	-0.3 to +30
EN/PSV, PGOOD, ILIM, to GND (V).....	-0.3 to +(V <sub>DD</sub> + 0.3)
SS, VOUT, FB, FBL, to GND (V).....	-0.3 to +(V <sub>DD</sub> + 0.3)
VDD to PGND (V) .....	-0.3 to +6
TON to AGND (V).....	-0.3 to +(VDD - 1.5)
ENL (V) .....	-0.3 to V <sub>IN</sub>
BST to LX (V) .....	-0.3 to +6.0
BST to PGND (V) .....	-0.3 to +35
AGND to PGND (V).....	-0.3 to +0.3
ESD Protection Level <sup>(1)</sup> (kV) .....	2

## Recommended Operating Conditions

Input Voltage (V) .....	3.0 to 28
VDD to PGND (V) .....	3.0 to 5.5
VOUT to PGND (V) .....	0.75 to 5.5

## Thermal Information

Storage Temperature (°C).....	-60 to +150
Maximum Junction Temperature (°C) .....	150
Operating Junction Temperature (°C) .....	-40 to +125
Thermal resistance, junction to ambient <sup>(2)</sup> (°C/W)	
High-side MOSFET .....	48
Low-side MOSFET .....	38
PWM controller and LDO thermal resistance .....	36
Peak IR Reflow Temperature (°C) .....	260

Exceeding the above specifications may result in permanent damage to the device or device malfunction. Operation outside of the parameters specified in the Electrical Characteristics section is not recommended.

### NOTES:

- (1) Tested according to JEDEC standard JESD22-A114.
- (2) Calculated from package in still air, mounted to 3 x 4.5 (in), 4 layer FR4 PCB with thermal vias under the exposed pad per JESD51 standards.

## Electrical Characteristics

Unless specified: V<sub>IN</sub> = 12V, T<sub>A</sub> = +25°C for Typ, -40 to +85 °C for Min and Max, T<sub>J</sub> < 125°C, V<sub>DD</sub> = +5V, per applicable Detailed Application Circuit

Parameter	Conditions	Min	Typ	Max	Units
<b>Input Supplies</b>					
VIN UVLO Threshold <sup>(1)</sup>	Sensed at ENL pin, rising edge	2.40	2.60	2.95	V
	Sensed at ENL pin, falling edge	2.235	2.40	2.565	
VIN UVLO Hysteresis	EN/PSV = High		0.2		V
VDD UVLO Threshold	Measured at VDD pin, rising edge	2.5		3.0	V
	Measured at VDD pin, falling edge	2.4		2.9	
VDD UVLO Hysteresis			0.2		V
VIN Supply Current	ENL, EN/PSV = 0V, V <sub>IN</sub> = 16V		8.5	20	μA
	Standby mode; ENL = V <sub>DD</sub> , EN/PSV = 0V		130		

**Electrical Characteristics (continued)**

Parameter	Conditions	Min	Typ	Max	Units
<b>Input Supplies (continued)</b>					
VDD Supply Current	ENL , EN/PSV = 0V		3	7	μA
	EN/PSV = V <sub>DD'</sub> , no load (f <sub>sw</sub> = 25kHz), V <sub>FB</sub> > 750mV		2		mA
	EN/PSV = V <sub>DD'</sub> , no load (f <sub>sw</sub> = 25kHz), V <sub>FB</sub> > 750mV		1		
	V <sub>DD</sub> = 5V, f <sub>sw</sub> = 250kHz, EN/PSV = floating , no load		4		
	V <sub>DD</sub> = 3V, f <sub>sw</sub> = 250kHz, EN/PSV = floating , no load		2.5		
FB On-Time Threshold	Static V <sub>IN</sub> and load, 0 to +85 °C	0.744	0.750	0.756	V
	Static V <sub>IN</sub> and load, -40 to +85 °C	0.742		0.758	V
Frequency Range	Continuous mode operation			1000	kHz
	Minimum f <sub>sw</sub> EN/PSV = V <sub>DD'</sub> no load		25		
Bootstrap Switch Resistance			10		Ω
<b>Switching MOSFET Resistance</b>					
R <sub>DSON</sub>	High Side FET		30		mΩ
	Low Side FET		10		
<b>Timing</b>					
On-Time	Continuous mode operation, V <sub>IN</sub> = 15V, V <sub>OUT</sub> = 5V, f <sub>sw</sub> = kHz, R <sub>TON</sub> = 300kΩ	2386	2650	2915	ns
	3V < V <sub>DD</sub> < 4.5V <sup>(2)</sup>				
Minimum On-Time			80		ns
Minimum Off-Time	V <sub>DD</sub> = 5V		250		ns
	V <sub>DD</sub> = 3V		370		
<b>Soft-Start</b>					
Soft-Start Current			2.75		μA
Soft-Start Voltage	When V <sub>OUT</sub> reaches regulation		1.5		V
<b>Analog Inputs/Outputs</b>					
VOUT Input Resistance			500		kΩ

**Electrical Characteristics (continued)**

Parameter	Conditions	Min	Typ	Max	Units
<b>Current Sense</b>					
Zero-Crossing Detector Threshold	LX - PGND	-3	0	+3	mV
<b>Power Good</b>					
Power Good Threshold	Upper limit, $V_{FB} >$ internal 750mV reference		+20		%
	Lower limit, $V_{FB} <$ internal 750mV reference		-10		%
Start-Up Delay Time (between PWM enable and PGOOD going high)	$V_{DD} = 3V, C_{SS} = 10nF$		7		ms
	$V_{DD} = 5V, C_{SS} = 10nF$		12		
Soft Start Threshold	When PGOOD logic switches high		64		%
Fault (noise immunity) Delay Time			5		$\mu s$
Leakage				1	$\mu A$
Power Good On-Resistance			10		$\Omega$
<b>Fault Protection</b>					
Valley Current Limit	$V_{DD} = 5V, R_{ILIM} = 6k\Omega$		5.1		A
	$V_{DD} = 3V, R_{ILIM} = 6k\Omega$		4.3		
Output Under-Voltage Fault	$V_{FB}$ with respect to internal 750mV reference, 8 consecutive switching cycles		-25		%
Smart Power-save Protection Threshold	$V_{FB}$ with respect to internal 750mV reference		+10		%
Over-Voltage Protection Threshold	$V_{FB}$ with respect to internal 750mV reference		+20		%
Over-Voltage Fault Delay			5		$\mu s$
Over-Temperature Shutdown	10°C hysteresis		155		°C
<b>Logic Inputs/Outputs</b>					
Logic Input High Voltage	ENL, minimum level		1		V
Logic Input Low Voltage	ENL, maximum level		0.4		V
EN/PSV Input for PSAVE Operation	Maximum level expressed in % of $V_{DD}$		100		%
	Minimum level expressed in % of $V_{DD}$		45		
EN/PSV Input for Forced Continuous Operation	Maximum level expressed in % of $V_{DD}$		42		%
	Minimum level		1		V

**Electrical Characteristics (continued)**

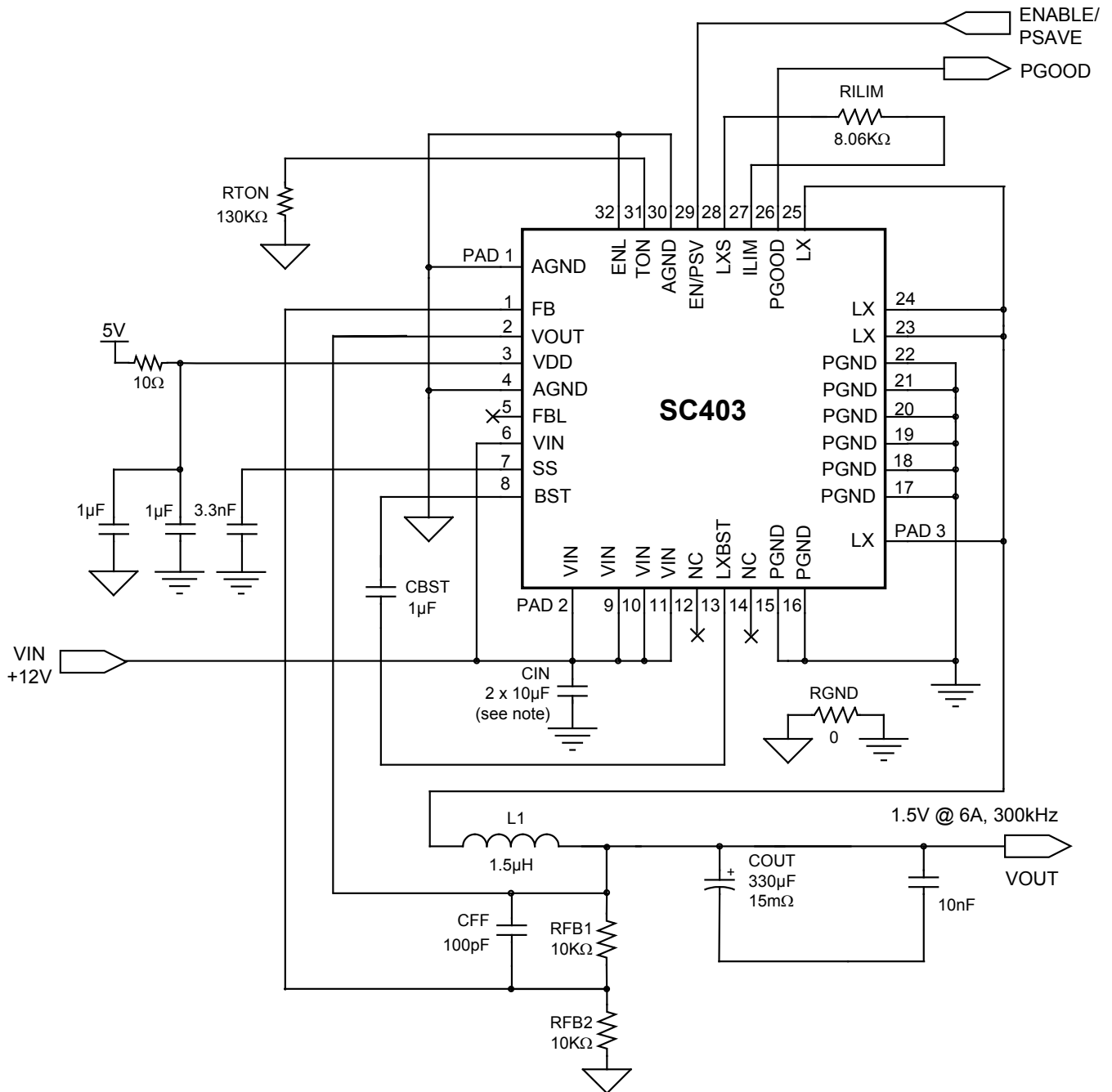
Parameter	Conditions	Min	Typ	Max	Units
<b>Logic Inputs/Outputs (continued)</b>					
EN/PSV Input for Disabling Switcher	Maximum level		0.4		V
	Minimum level		0		
EN/PSV Input Bias Current	EN/PSV = VDD or AGND	-8		+8	μA
ENL Input Bias Current	$V_{IN} = 16V$		11	18	μA
FBL, FB Input Bias Current	FBL, FB = VDD or AGND	-1		+1	μA
<b>Linear Regulator</b> (The LDO is shorted to the VDD pin internally.)					
FBL Accuracy	LDO load = 10mA	0.735	0.75	0.765	V
LDO Current Limit	Short-circuit protection, $V_{IN} = 12V, V_{DD} < 0.75V$		65		mA
	Start-up and foldback, $V_{IN} = 12V, 0.75 < V_{DD} < 90\%$ of final $V_{DD}$ value		115		
	Operating current limit, $V_{IN} = 12V, V_{DD} > 90\%$ of final $V_{DD}$ value	135	200		
LDO to VOUT Switch-over Threshold <sup>(3)</sup>		-140		+140	mV
LDO to VOUT Non-switch-over Threshold <sup>(3)</sup>		-450		+450	mV
LDO to VOUT Switch-over Resistance	$V_{OUT} = +5V$		2		Ω
LDO Drop Out Voltage <sup>(4)</sup>	From $V_{IN}$ to $V_{DD}, V_{DD} = +5V, I_{LDO} = 100mA$		1.2		V

**Notes:**

- (1)  $V_{IN}$  UVLO is programmable using a resistor divider from VIN to ENL to AGND pins. The ENL voltage is compared to an internal reference.
- (2) For VDD less than 4.5V, the on-time may be limited by the VDD supply voltage and by the  $V_{IN}$ . See the TON limitation and VDD supply voltage section in the applications Information.
- (3) The switch-over threshold is the maximum voltage differential between the VDD and VOUT pins which ensures that LDO will internally switch-over to VOUT. The non-switch-over threshold is the minimum voltage differential between the LDO and VOUT pins which ensures that LDO will not switch-over to VOUT.
- (4) The LDO drop out voltage is the voltage at which the LDO output drops 2% below the no load regulation value.





**Detailed Application Circuit-2**
**External 5V Used as Bias**

**Key Components**

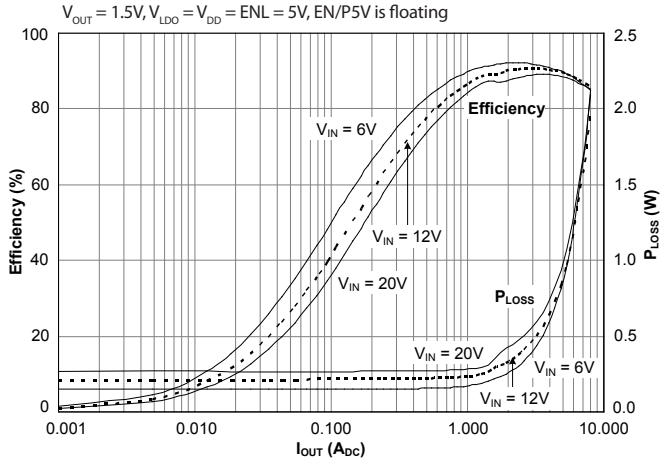
Component	Value	Manufacturer	Part Number	Web
CIN	2 x 10μF/25V	Murata	GRM32DR71E106KA12L	<a href="http://www.murata.com">www.murata.com</a>
COUT	330μF/9mΩ	Panasonic	EEF-SX0E331ER	<a href="http://www.panasonic.com">www.panasonic.com</a>
L1	1.5μH/6.7mΩ	Cyntec	PCMB065T-1R5MS	<a href="http://www.cyntec.com">www.cyntec.com</a>

NOTE: The quantity of 10μF input capacitors required varies with the application requirements.

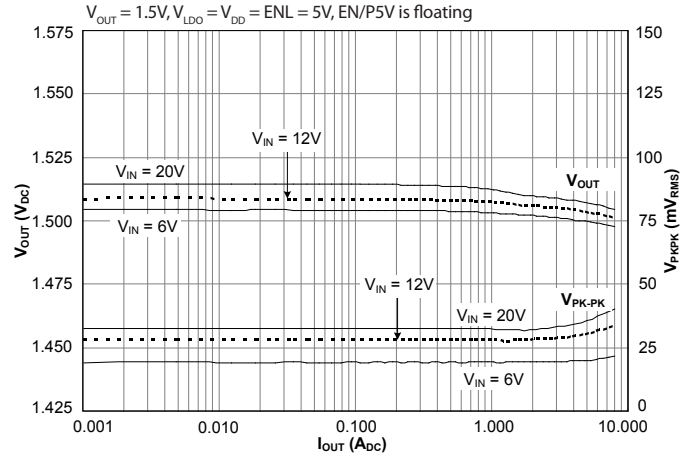
## Typical Characteristics

Characteristics in this section are based on using the applicable Detailed Application Circuit.

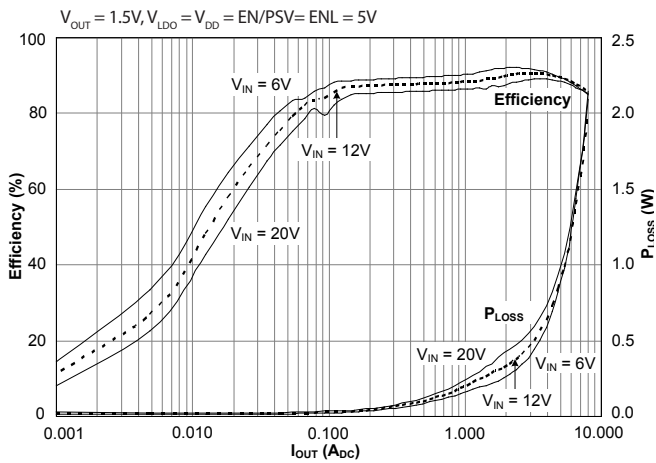
### Efficiency vs. Load — Forced Continuous Mode



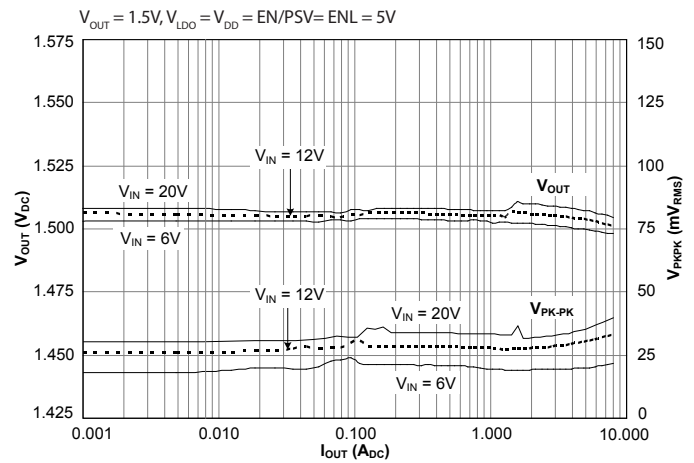
### $V_{OUT}$ vs. Load — Forced Continuous Mode



### Efficiency vs. Load — PSAVE Mode



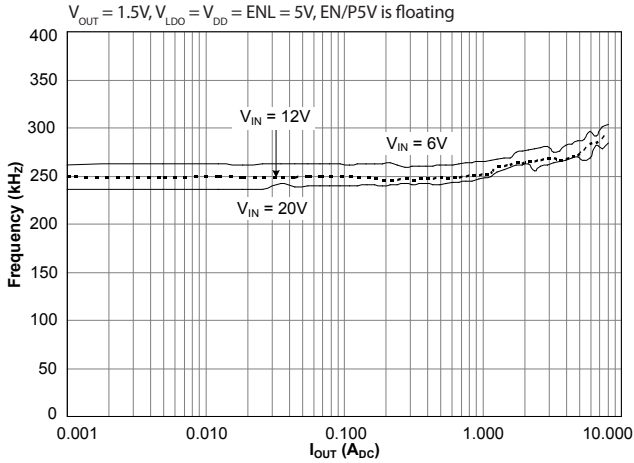
### $V_{OUT}$ vs. Load — PSAVE Mode



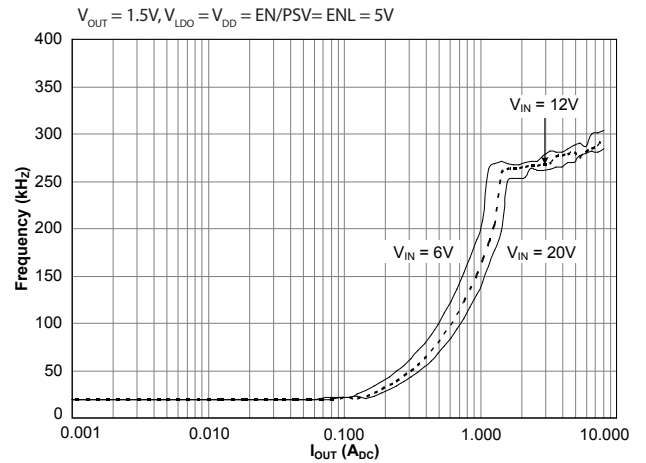
## Typical Characteristics (continued)

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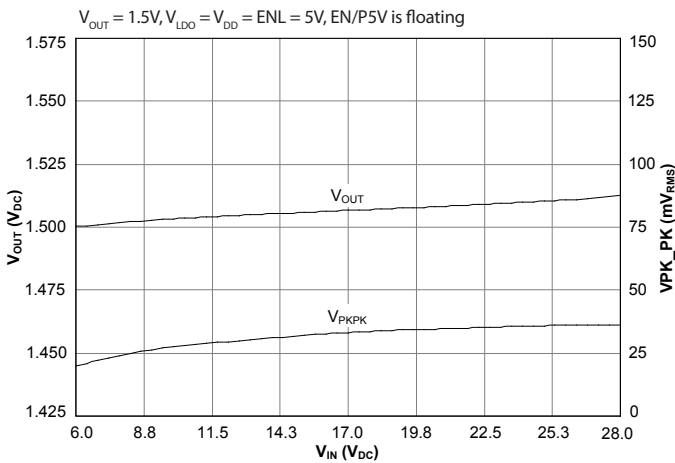
### Frequency vs. Load — Forced Continuous Mode



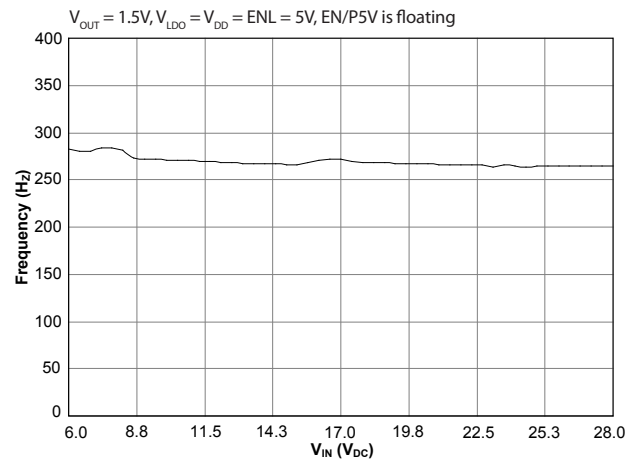
### Frequency vs. Load — PSAVE Mode



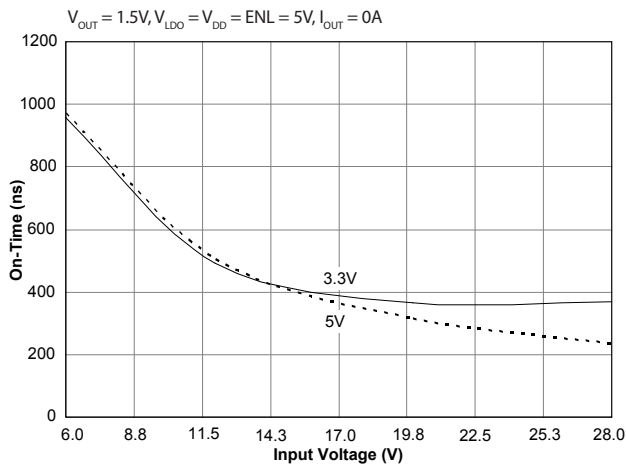
### $V_{OUT}$ vs. Line — Forced Continuous Mode



### Frequency vs. Line — FCM Mode



### On-Time vs. Line

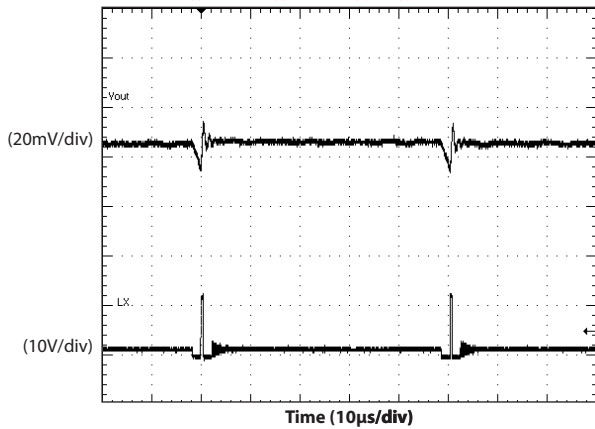


## Typical Characteristics (continued)

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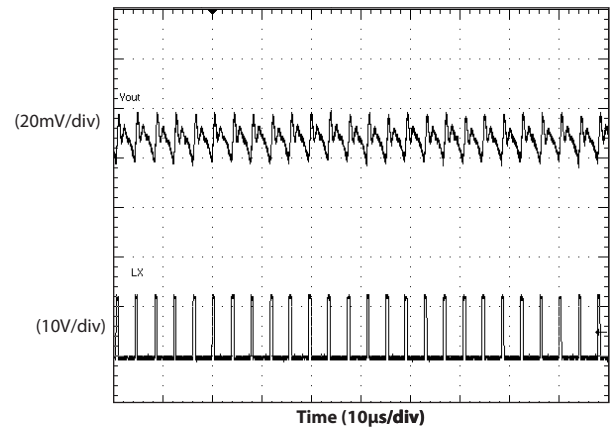
### Ultrasonic Powersave Mode — No Load

$V_{IN} = 12V, V_{OUT} = 1.5V, I_{OUT} = 0A, V_{LDO} = V_{DD} = EN/PSV = ENL = 3.3V$



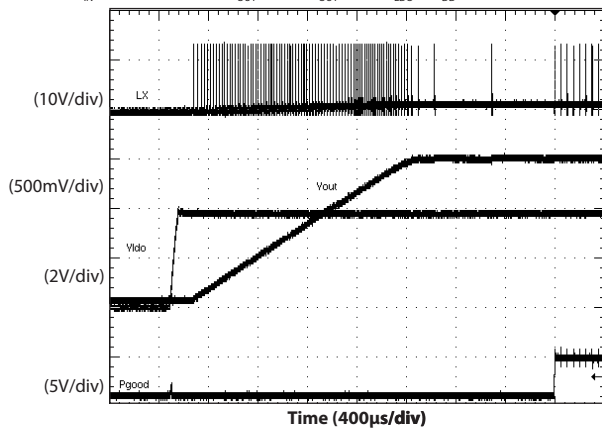
### Forced Continuous Mode — No Load

$V_{IN} = 12V, V_{OUT} = 1.5V, I_{OUT} = 0A, V_{LDO} = V_{DD} = ENL = 3.3V, EN/PSV = \text{floating}$



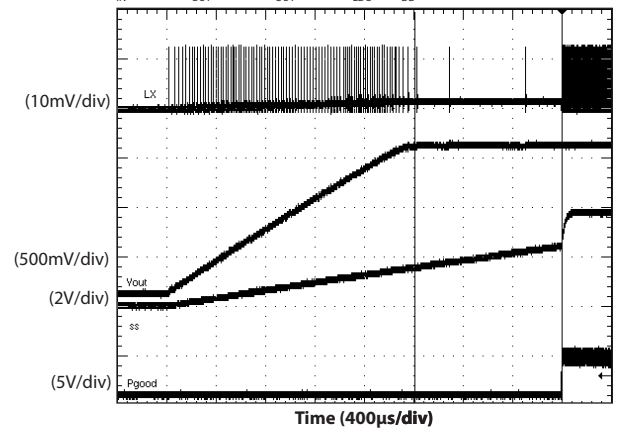
### Self-Biased Start-Up — Power Good True

$V_{IN} = 0V \text{ to } 12V \text{ step}, V_{OUT} = 1.5V, I_{OUT} = 0A, V_{LDO} = V_{DD} = EN/PSV = ENL = 3.3V$



### Enabled Loaded Output

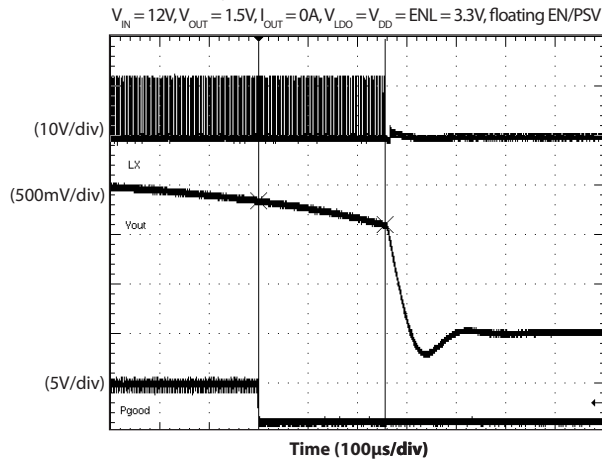
$V_{IN} = 12V, V_{OUT} = 1.5V, I_{OUT} = 1A, V_{LDO} = V_{DD} = ENL = EN/PSV = \text{floating}$



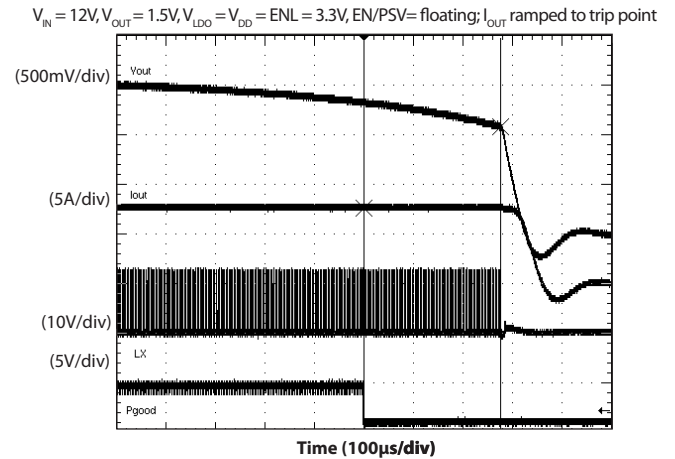
## Typical Characteristics (continued)

Characteristics in this section are based on using the applicable Detailed Application Circuit.

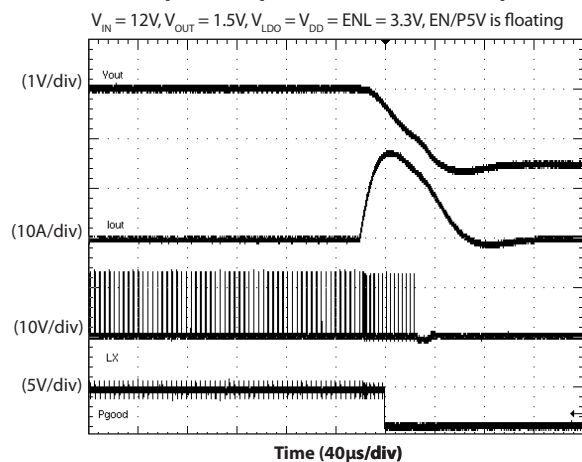
### Output Under-voltage Response — Normal Operation



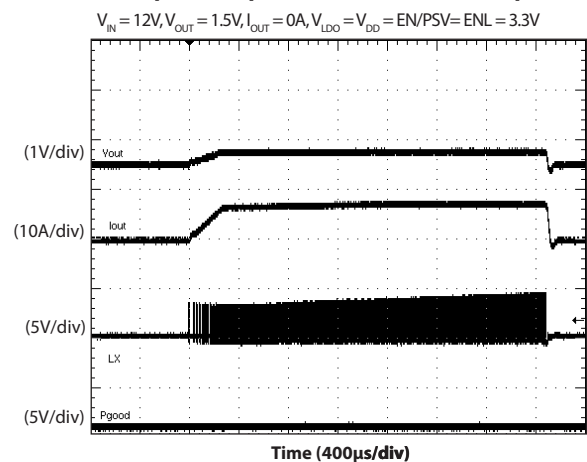
### Output Over-current Response — Normal Operation



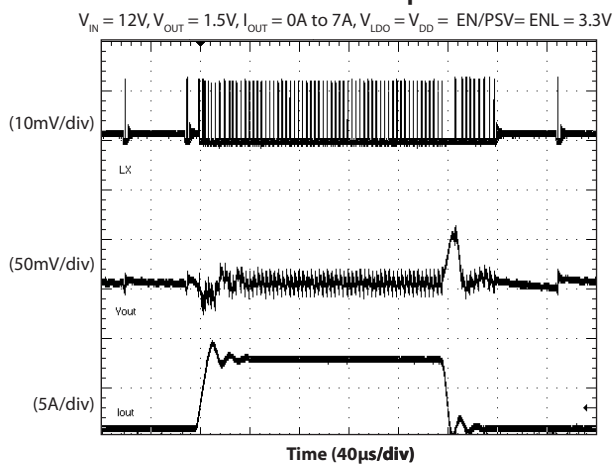
### Shorted Output Response — Normal Operation



### Shorted Output Response — Soft-start Operation

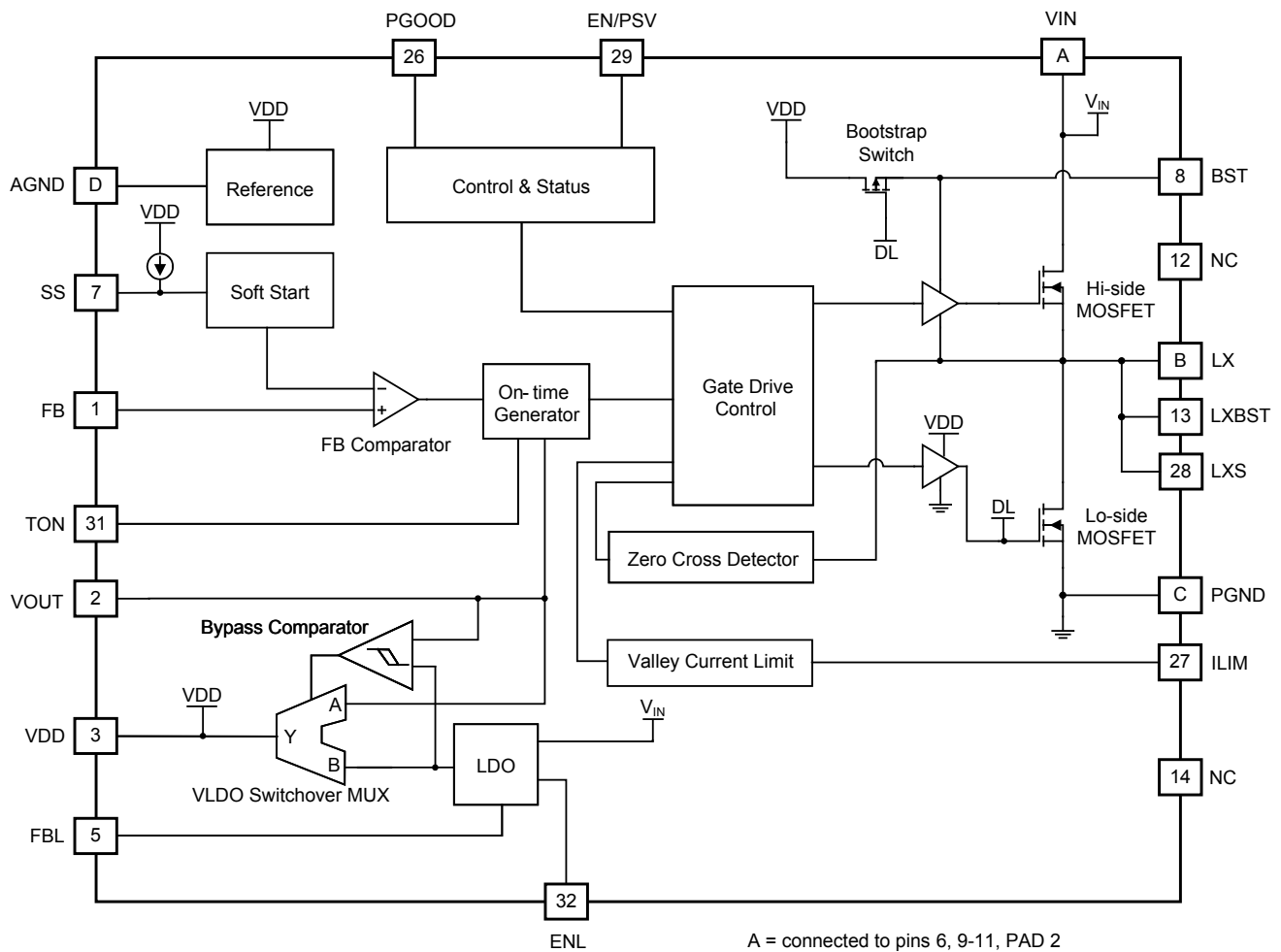


### Transient Response



## Pin Descriptions

Pin #	Pin Name	Pin Function
1	FB	Feedback input for switching regulator used to program the output voltage — connect to an external resistor divider from VOUT to AGND.
2	VOUT	Switcher output voltage sense pin — also the input to the internal switch-over between VOUT and VLDO. The voltage at this pin must be less than or equal to the voltage at the VDD pin.
3	VDD	Bias supply for the IC — when using the internal LDO as a bias power supply, the VDD is the LDO output. When using an external power supply to bias the IC, the LDO output should be disabled.
4, 30, PAD 1	AGND	Analog ground
5	FBL	Feedback input for the internal LDO — connect to an external resistor divider from VDD to AGND to program the LDO output.
6, 9-11, PAD 2	VIN	Input supply voltage
7	SS	The soft start time is programmed by an internal current source charging a capacitor on this pin.
8	BST	Bootstrap pin — connect a capacitor of at least 100nF from BST to LX to develop the floating supply for the high-side gate drive.
12	NC	No connection
13	LXBST	LX Boost — connect to the BST capacitor.
23-25, PAD 3	LX	Switching (phase) node
14	NC	No connection
15-22	PGND	Power ground
26	PGOOD	Open-drain power good indicator — high impedance indicates power is good. An external pull-up resistor is required.
27	ILIM	Current limit sense pin — used to program the current limit by connecting a resistor from ILIM to LXS.
28	LXS	LX sense — connects to $R_{ILIM}$ .
29	EN/PSV	Enable/power-save input for the switching regulator — connect to AGND to disable the switching regulator. Float to operate in forced continuous mode (PSAVE disabled). Connect to VDD to operate with ultrasonic PSAVE mode enabled.
31	TON	On-time programming input — set the on-time by connecting through a resistor to AGND.
32	ENL	Enable input for the LDO — connect ENL to AGND to disable the LDO. Drive with logic signal for logic control, or program the VIN UVLO with a resistor divider between VIN, ENL, and AGND pins.

**Block Diagram**


A = connected to pins 6, 9-11, PAD 2  
 B = connected to pins 23-25, PAD 3  
 C = connected to pins 15-22  
 D = connect to pins 4, 30, PAD 1

## Applications Information

### Synchronous Buck Converter

The SC403 is a step down synchronous DC-DC buck converter with integrated power MOSFETs and a 200mA programmable LDO. The device operates at a current up to 6A at very high efficiency. A space saving 5x5 (mm) 32-pin package is used. The programmable operating frequency of up to 1MHz enables optimizing the configuration for PCB area and efficiency.

The buck controller uses a pseudo-fixed frequency adaptive on-time control. This control method allows fast transient response which permits the use of smaller output capacitors.

### Input Voltage Requirements

The SC403 requires two input supplies for normal operation:  $V_{IN}$  and  $V_{DD}$ .  $V_{IN}$  operates over a wide range from 3V to 28V.  $V_{DD}$  requires a supply voltage between 3V to 5V that can be an external source or the internal LDO from  $V_{IN}$ .

### Power Up Sequence

The SC403 initiates a start up when  $V_{IN}$ ,  $V_{DD}$ , and EN/PSV pins are above the applicable thresholds. When using an external bias supply for the  $V_{DD}$  voltage, it is recommended that the  $V_{DD}$  is applied to the device only after the  $V_{IN}$  voltage is present because  $V_{DD}$  cannot exceed  $V_{IN}$  at any time. A 10 $\Omega$  resistor must be placed between the external  $V_{DD}$  supply and the VDD pin to avoid damage to the device during power-up and or shutdown situations where  $V_{DD}$  could exceed  $V_{IN}$  unexpectedly.

### Shutdown

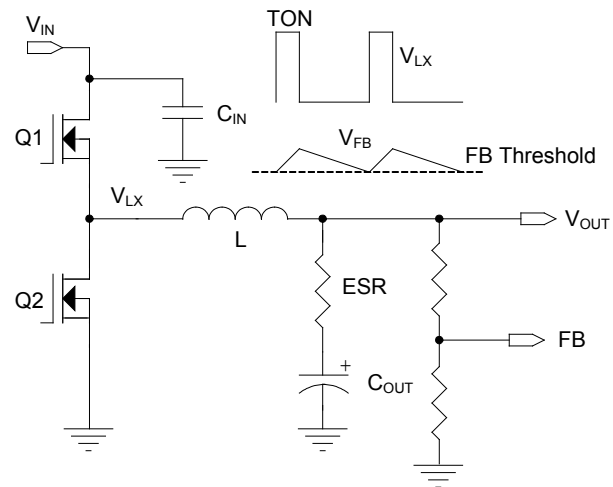
The SC403 can be shutdown by pulling either VDD or EN/PSV pin below its threshold. When using an external supply voltage for  $V_{DD}$ , the VDD pin must be deactivated while the  $V_{IN}$  voltage is still present. A 10 $\Omega$  resistor must be placed between the external  $V_{DD}$  supply and the VDD pin to avoid damage to the device.

When the VDD pin is active and EN/PSV is at low logic level, the output voltage discharges through an internal FET.

### Pseudo-fixed Frequency Adaptive On-time Control

The PWM control method used by the SC403 is pseudo-fixed frequency, adaptive on-time, as shown in Figure 1.

The ripple voltage generated at the output capacitor ESR is used as a PWM ramp signal. This ripple is used to trigger the controller on-time.



**Figure 1 — PWM Control Method,  $V_{OUT}$  Ripple**

The adaptive on-time is determined by an internal one-shot timer. When the one-shot is triggered by the output ripple, the device sends a single on-time pulse to the high-side MOSFET. The pulse period is determined by  $V_{OUT}$  and  $V_{IN}$ . The period is proportional to output voltage and inversely proportional to input voltage. With this adaptive on-time arrangement, the device automatically anticipates the on-time needed to regulate  $V_{OUT}$  for the present  $V_{IN}$  condition and at the selected frequency.

The advantages of adaptive on-time control are:

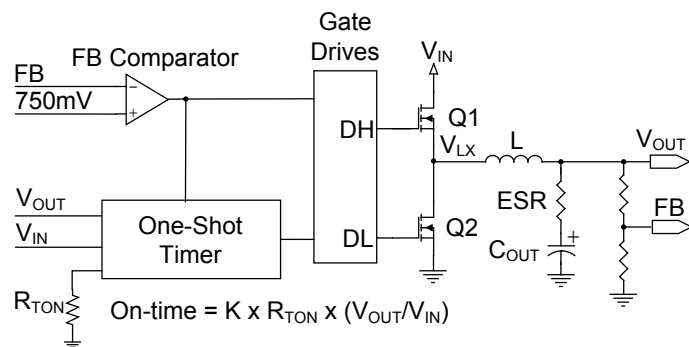
- Predictable operating frequency compared to other variable frequency methods.
- Reduced component count by eliminating the error amplifier and compensation components.
- Reduced component count by removing the need to sense and control inductor current.
- Fast transient response — the response time is controlled by a fast comparator instead of a typically slow error amplifier.
- Reduced output capacitance due to fast transient response



## Applications Information (continued)

### One-Shot Timer and Operating Frequency

One-shot timer operation is shown in Figure 2. The FB Comparator output goes high when  $V_{FB}$  is less than the internal 750mV reference. This feeds into the gate drive and turns on the high-side MOSFET, and starts the one-shot timer. The one-shot timer uses an internal comparator and a capacitor. One comparator input is connected to  $V_{OUT}$ , the other input is connected to the capacitor. When the on-time begins, the internal capacitor charges from zero volts through a current which is proportional to  $V_{IN}$ . When the capacitor voltage reaches  $V_{OUT}$ , the on-time is completed and the high-side MOSFET turns off.



**Figure 2 — On-Time Generation**

This method automatically produces an on-time that is proportional to  $V_{OUT}$  and inversely proportional to  $V_{IN}$ . Under steady-state conditions, the switching frequency can be determined from the on-time by the following equation.

$$f_{SW} = \frac{V_{OUT}}{T_{ON} \times V_{IN}}$$

The SC403 uses an external resistor to set the on-time which indirectly sets the frequency. The on-time can be programmed to provide an operating frequency from 200kHz to 1MHz using a resistor between the TON pin and ground. The resistor value is selected by the following equation.

$$R_{TON} = \frac{(t_{ON} - 10ns) \times V_{IN}}{25pF \times V_{OUT}}$$

The maximum  $R_{TON}$  value allowed is shown by the following equation.

$$R_{TON\_MAX} = \frac{V_{IN\_MIN}}{10 \times 1.5\mu A}$$

Immediately after the on-time, the DL (drive signal for the low side FET) output drives high to turn on the low-side MOSFET. DL has a minimum high time of  $\sim 320ns$ , after which DL continues to stay high until one of the following occurs:

- VFB falls below the 750mV reference
- The zero cross detector senses that the voltage on the LX node is below ground. Power save is activated eight switching cycles after a zero crossing is detected.

### TON limitations and $V_{DD}$ Supply Voltage

For  $V_{DD}$  below 4.5V, the TON accuracy may be limited by the input voltage.

The original  $R_{TON}$  equation is accurate if  $V_{IN}$  satisfies the relationship over the entire  $V_{IN}$  range, as follows.

$$V_{IN} < (V_{DD} - 1.6V) \times 10$$

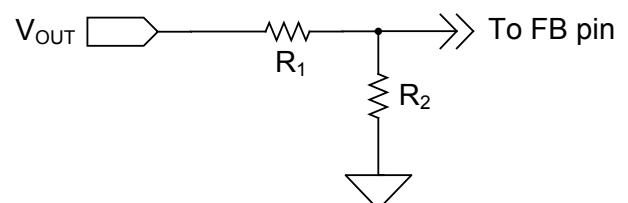
If  $V_{IN}$  exceeds  $(V_{DD} - 1.6V) \times 10$ , for all or part of the  $V_{IN}$  range, the  $R_{TON}$  equation is not accurate. In all cases where  $V_{IN} > (V_{DD} - 1.6V) \times 10$ , the  $R_{TON}$  equation must be modified, as follows.

$$R_{TON} = \frac{(T_{ON} - 10ns) \times (V_{DD} - 1.6V) \times 10}{25pF \times V_{OUT}}$$

Note that when  $V_{IN} > (V_{DD} - 1.6V) \times 10$ , the actual on-time is fixed and does not vary with  $V_{IN}$ . When operating in this condition, the switching frequency will vary inversely with  $V_{IN}$  rather than approximating a fixed frequency.

### $V_{OUT}$ Voltage Selection

The switcher output voltage is regulated by comparing  $V_{OUT}$  as seen through a resistor divider at the FB pin to the internal 750mV reference voltage, see Figure 3.



**Figure 3 — Output Voltage Selection**

## Applications Information (continued)

Note that this control method regulates the valley of the output ripple voltage, not the DC value. The DC output voltage  $V_{OUT}$  is offset by the output ripple according to the following equation.

$$V_{OUT} = 0.75 \times \left( 1 + \frac{R_1}{R_2} \right) + \left( \frac{V_{RIPPLE}}{2} \right)$$

When a large capacitor is placed in parallel with  $R_1$  ( $C_{TOP}$ )  $V_{OUT}$  is shown by the following equation.

$$V_{OUT} = 0.75 \times \left( 1 + \frac{R_1}{R_2} \right) + \left( \frac{V_{RIPPLE}}{2} \right) \times \sqrt{\frac{1 + (R_1 \omega C_{TOP})^2}{1 + \left( \frac{R_2 \times R_1}{R_2 + R_1} \omega C_{TOP} \right)^2}}$$

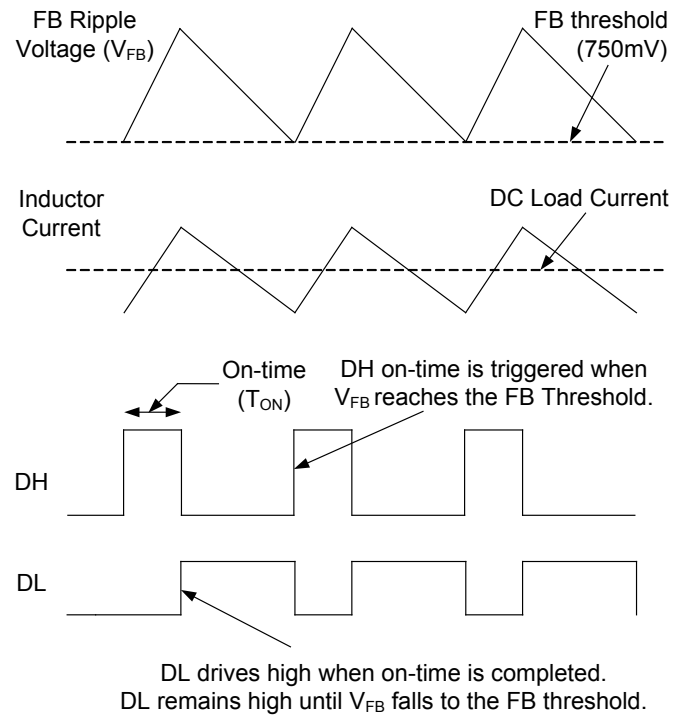
### Enable and Power Save Input

The EN/PSV input is used to enable or disable the switching regulator. When EN/PSV is low (grounded), the switching regulator is off and in its lowest power state. When off, the output of the switching regulator soft-discharges the output into a  $15\Omega$  internal resistor via the  $V_{OUT}$  pin. When EN/PSV is allowed to float, the pin voltage will float to 33% of the voltage at VDD. The switching regulator turns on with PSAVE (power save) disabled and all switching is in forced continuous mode.

When EN/PSV is high (above 45% of the voltage at VDD), the switching regulator turns on with ultrasonic power-save enabled. The ultrasonic PSAVE operation maintains a minimum switching frequency of 25kHz, for applications with stringent audio requirements.

### Forced Continuous Mode Operation

The SC403 operates the switcher in FCM (Forced Continuous Mode) by floating the EN/PSV pin (see Figure 4). In this mode one of the power MOSFETs is always on, with no intentional dead time other than to avoid cross-conduction. This feature results in uniform frequency across the full load range with the trade-off being poor efficiency at light loads due to the high-frequency switching of the MOSFETs. DH is the gate signal driving the upper MOSFET. DL is the lower gate signal driving the lower MOSFET.



**Figure 4 — Forced Continuous Mode Operation**

### Ultrasonic PSAVE Operation

The SC403 provides ultrasonic PSAVE operation at light loads, with the minimum operating frequency fixed at 25kHz. This is accomplished using an internal timer that monitors the time between consecutive high-side gate pulses. If the time exceeds  $40\mu s$ , DL drives high to turn the low-side MOSFET on. This draws current from  $V_{OUT}$  through the inductor, forcing both  $V_{OUT}$  and  $V_{FB}$  to fall. When  $V_{FB}$  drops to the 750mV threshold, the next DH on-time is triggered. After the on-time is completed the high-side MOSFET is turned off and the low-side MOSFET turns on. The low-side MOSFET remains on until the inductor current ramps down to zero, at which point the low-side MOSFET is turned off.

## Applications Information (continued)

Because the on-times are forced to occur at intervals no greater than  $40\mu\text{s}$ , the frequency will not fall below  $\sim 25\text{kHz}$ . Figure 5 shows ultrasonic PSAVE operation.

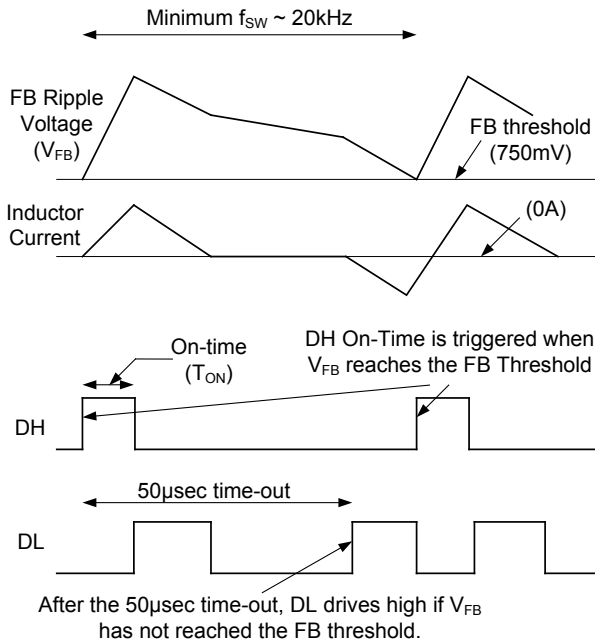


Figure 5 — Ultrasonic PSAVE Operation

### Smart PSAVE Protection

Active loads may leak current from a higher voltage into the switcher output. Under light load conditions with PSAVE enabled, this can force  $V_{OUT}$  to slowly rise and reach the over-voltage threshold, resulting in a hard shutdown. Smart PSAVE prevents this condition. When the FB voltage exceeds 10% above nominal, the device immediately disables PSAVE, and DL drives high to turn on the low-side MOSFET. This draws current from  $V_{OUT}$  through the inductor and causes  $V_{OUT}$  to fall. When  $V_{FB}$  drops back to the 750mV trip point, a normal  $t_{ON}$  switching cycle begins. This method prevents a hard OVP shutdown and also cycles energy from  $V_{OUT}$  back to  $V_{IN}$ . It also minimizes operating power by avoiding forced conduction mode operation. Figure 6 shows typical waveforms for the Smart PSAVE feature.

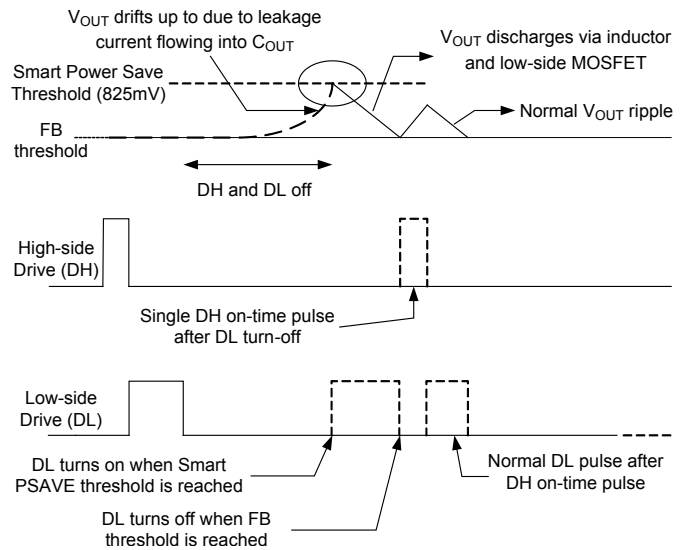


Figure 6 — Smart PSAVE

### SmartDrive™

For each DH pulse the DH driver initially turns on the high-side MOSFET at a lower speed, allowing a softer, smooth turn-off of the low-side diode. Once the diode is off and the LX voltage has risen 1V above PGND, the SmartDrive circuit automatically drives the high-side MOSFET on at a rapid rate. This technique reduces switching power loss while maintaining high efficiency and also avoids the need for snubbers or series resistors in the gate drive.

### Current Limit Protection

Programmable current limiting is accomplished by using the  $R_{DS_{ON}}$  of the lower MOSFET for current sensing. The current limit is set by the  $R_{ILIM}$  resistor. The  $R_{ILIM}$  resistor connects from the ILIM pin to the LX pin which is also the drain of the low-side MOSFET. When the low-side MOSFET is on, an internal  $\sim 10\mu\text{A}$  current flows from the ILIM pin and through the  $R_{ILIM}$  resistor, creating a voltage drop across the resistor. While the low-side MOSFET is on, the inductor current flows through it and creates a voltage across the  $R_{DS_{ON}}$ . The voltage across the MOSFET is negative with respect to ground. If this MOSFET voltage drop exceeds the voltage across  $R_{ILIM}$ , the voltage at the ILIM pin will be negative and current limit will activate. The current limit then keeps the low-side MOSFET on and will not allow another high-side on-time, until the current in the low-side MOSFET reduces enough to bring the ILIM voltage back up to zero. This method regulates the inductor valley current at the level shown by ILIM in Figure 7.

## Applications Information (continued)

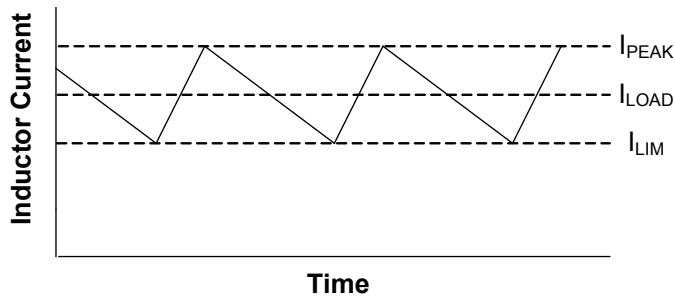


Figure 7 — Valley Current Limit

Setting the valley current limit to 6A results in a peak inductor current of 6A plus the peak-to-peak ripple current. In this situation, the average (load) current through the inductor is 6A plus one-half the peak-to-peak ripple current.

The internal 10 $\mu$ A current source is temperature compensated at 4100ppm in order to provide tracking with the  $R_{DS_{ON}}$ .

The  $R_{ILIM}$  value is calculated by the following equation.

$$R_{ILIM} = 1176 \times I_{LIM} \times [0.088 \times (5V - V_{DD}) + 1] (\Omega)$$

where  $I_{LIM}$  is in Amps.

When selecting a value for  $R_{ILIM}$  do not exceed the absolute maximum voltage value for the ILIM pin. Note that because the low-side MOSFET with low  $R_{DS_{ON}}$  is used for current sensing, the PCB layout, solder connections, and PCB connection to the LX node must be done carefully to obtain good results.  $R_{ILIM}$  should be connected directly to LXS (pin 28).

### Soft-Start of PWM Regulator

SC403 has a programmable soft-start time that is controlled by an external capacitor at the SS pin. After the controller meets both UVLO and EN/PSV thresholds, the controller has an internal current source of 2.75 $\mu$ A flowing through the SS pin to charge the capacitor. During the start up process (Figure 8), 50% of the voltage at the SS pin is used as the reference for the FB comparator. The PWM comparator issues an on-time pulse when the voltage at the FB pin is less than 50% of the SS pin. As result, the output voltage follows the SS start voltage. The output voltage reaches and maintains regulation when the soft start voltage is  $\geq 1.5V$ . The time between the first LX pulse and when  $V_{OUT}$  meets regulation is the soft start time ( $t_{SS}$ ). The calculation for the soft-start time is shown by the following equation.

$$t_{SS} = C_{SS} \times \frac{1.5V}{2.75\mu A}$$

The voltage at the SS pin continues to ramp up and eventually is equal to 64% of  $V_{DD}$ . After soft start completes, the FB pin voltage is compared to an internal reference of 0.75V. The delay time between the  $V_{OUT}$  regulation point and PGOOD going high is shown by the following equation.

$$t_{PGOOD-DELAY} = \frac{C_{SS} \times (0.64 \times V_{DD} - 1.5V)}{2.75\mu A}$$

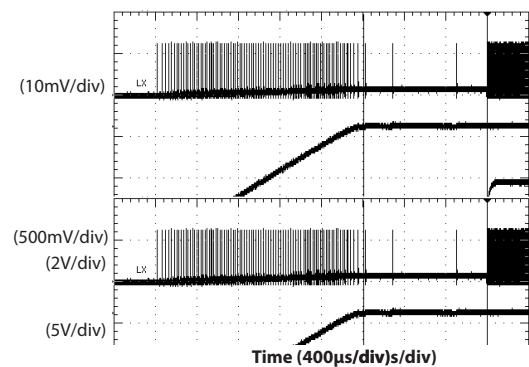


Figure 8 — Soft-start Timing Diagram

### Pre-Bias Startup

SC403 can start up as if in a soft-start condition with an existing output voltage level. The soft start time is still the same as normal start up (when the output voltage starts from zero). The output voltage starts to ramp up when one-half of the voltage at SS pin meets the pre-charge FB voltage level. Pre-bias startup is achieved by turning off the lower gate when the inductor current falls below zero. This method prevents the output voltage from decreasing.

### Power Good Output

The PGOOD (power good) output is an open-drain output which requires a pull-up resistor. When the voltage at the FB pin is 10% below the nominal voltage, PGOOD is pulled low. It is held low until the output voltage returns above 92% of nominal.

PGOOD will transition low if the  $V_{FB}$  pin exceeds +20% of nominal, which is also the over-voltage shutdown threshold. PGOOD also pulls low if the EN/PSV pin is low when  $V_{DD}$  voltage is present.

## Applications Information (continued)

### Output Over-Voltage Protection

Over-voltage protection becomes active as soon as the device is enabled. The threshold is set at  $750\text{mV} + 20\%$  ( $900\text{mV}$ ). When  $V_{FB}$  exceeds the OVP threshold, DL latches high and the low-side MOSFET is turned on. DL remains high and the controller remains off, until the EN/PSV input is toggled or VDD is cycled. There is a  $5\mu\text{s}$  delay built into the OVP detector to prevent false transitions. PGOOD is also low after an OVP event.

### Output Under-Voltage Protection

When  $V_{FB}$  falls 25% below its nominal voltage (falls to  $562.5\text{mV}$ ) for eight consecutive switching cycles, the switcher is shut off and the DH and DL drives are pulled low to tri-state the MOSFETs. The controller stays off until EN/PSV is toggled or VDD is cycled.

### VDD UVLO, and POR

UVLO (Under-Voltage Lock-Out) circuitry inhibits switching and tri-states the DH/DL drivers until  $V_{DD}$  rises above  $3.0\text{V}$ . An internal POR (Power-On Reset) occurs when  $V_{DD}$  exceeds  $3.0\text{V}$ , which resets the fault latch and soft-start counter to prepare for soft-start. The SC403 then begins a soft-start cycle. The PWM will shut off if VDD falls below  $2.4\text{V}$ .

### LDO Regulator

SC403 has an option to bias the switcher by using an internal LDO from  $V_{IN}$ . The LDO output is connected to VDD internally. The output of the LDO is programmable by using external resistors from the VDD pin to AGND. The feedback pin (FBL) for the LDO is regulated to  $750\text{mV}$  (see Figure 9).

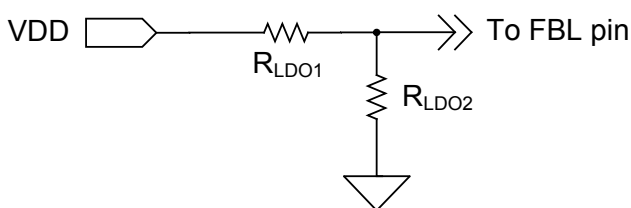


Figure 9 — LDO Voltage Divider

The LDO output voltage is set by the following equation.

$$V_{LDO} = 750\text{mV} \times \left( 1 + \frac{R_{LDO1}}{R_{LDO2}} \right)$$

A minimum  $0.1\mu\text{F}$  capacitor referenced to AGND is required along with a minimum  $1.0\mu\text{F}$  capacitor referenced to PGND to filter the gate drive pulses. Refer to the layout guidelines section for component placement suggestions.

### LDO ENL Functions

The ENL input is used to control the internal LDO. When ENL is low (grounded), the LDO is off. When ENL is above the  $V_{IN}$  UVLO threshold, the LDO is enabled and the switcher is also enabled if EN/PSV and VDD meet the thresholds.

The ENL pin also acts as the switcher UVLO (under-voltage lockout) for the  $V_{IN}$  supply. The  $V_{IN}$  UVLO voltage is programmable via a resistor divider at the VIN, ENL and AGND pins.

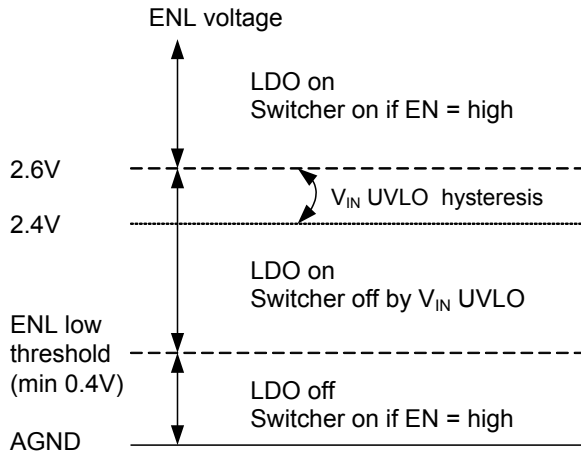
If the ENL pin transitions from high to low within 2 switching cycles and is less than  $1\text{V}$ , then the LDO will turn off but the switcher remains on. If the ENL goes below the  $V_{IN}$  UVLO threshold and stays above  $1\text{V}$ , then the switcher will turn off but the LDO remains on. The  $V_{IN}$  UVLO function has a typical threshold of  $2.6\text{V}$  on the  $V_{IN}$  rising edge. The falling edge threshold is  $2.4\text{V}$ .

Note that it is possible to operate the switcher with the LDO disabled, but the ENL pin must be below the logic low threshold ( $0.4\text{V}$  maximum). In this case, the UVLO function for the input voltage cannot be used. The table below summarizes the function of the ENL and EN pins, with respect to the rising edge of ENL.

EN	ENL	LDO status	Switcher status
low	low, $< 0.4\text{V}$	off	off
high	low, $< 0.4\text{V}$	off	on
low	high, $< 2.6\text{V}$	on	off
high	high, $< 2.6\text{V}$	on	off
low	high, $> 2.6\text{V}$	on	off
high	high, $> 2.6\text{V}$	on	on

## Applications Information (continued)

Figure 10 shows the ENL voltage thresholds and their effect on LDO and switcher operation.



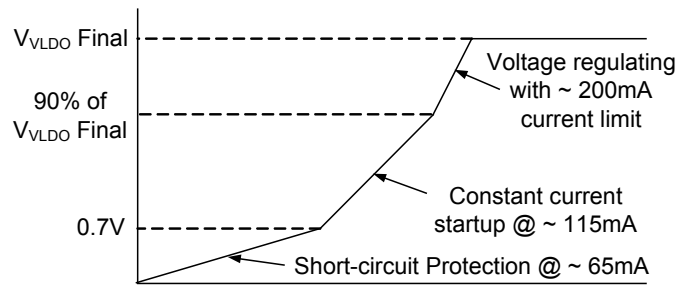
**Figure 10 — ENL Threshold**

Before start-up, the LDO checks the status of the following signals to ensure proper operation can be maintained.

1. ENL pin
2.  $V_{IN}$  input voltage

When the ENL pin is high and  $V_{IN}$  is above the UVLO point, the LDO will begin start-up. During the initial phase, when the  $V_{DD}$  voltage (which is the LDO output voltage) is less than 0.75V, the LDO initiates a current-limited start-up (typically 65mA) to charge the output capacitors while protecting from a short circuit event. When  $V_{DD}$  is greater than 0.75V but still less than 90% of its final value (as sensed at the FBL pin), the LDO current limit is increased to ~115mA. When  $V_{DD}$  has reached 90% of the final value (as sensed at the FBL pin), the LDO current limit is increased to ~200mA and the LDO output is quickly driven to the nominal value by the internal LDO regulator. It is recommended that during LDO start-up to hold the PWM switching off until the LDO has reached 90% of the final value. This prevents overloading the current-limited LDO output during the LDO start-up.

Due to the initial current limitations on the LDO during power up (Figure 11), any external load attached to the VDD pin must be limited to 20mA before the LDO has reached 90% of its final regulation value.



**Figure 11 — LDO Start-Up**

### LDO Switch-Over Operation

The switch-over function is provided to increase efficiency by using the more efficient DC-DC converter to power the LDO output, avoiding the less efficient LDO regulator when possible. The switch-over function connects the VDD pin directly to the VOUT pin using an internal switch. When the switch-over is complete the LDO is turned off, which results in power savings and maximizes efficiency. If the LDO output is used to bias the SC403, then after switch-over the device is self-powered from the switching regulator with the LDO turned off.

The switch-over logic waits for 32 switching cycles before it starts the switch-over. When the LDO is already in regulation and the DC-DC converter is later enabled, as soon as the PGOOD output goes high, the 32 cycles are started. The voltages at the VDD and VOUT pins are then compared; if the two voltages are within  $\pm 300\text{mV}$  of each other, the VDD pin connects to the VOUT pin using an internal switch, and the LDO is turned off.

### Switch-over Limitations on VOUT, ENL, and VDD

Because the internal switch-over circuit always compares the VOUT and VDD pins at start-up, there are limitations on permissible combinations of these pins. Consider the case where  $V_{OUT}$  is programmed to 3.0V and  $V_{LDO}$  is programmed to 3.3V. After start-up, the device would connect VOUT to VDD and disable the LDO, since the two voltages are within the  $\pm 300\text{mV}$  switch-over window. To avoid unwanted switch-over, the minimum difference between the voltages for  $V_{OUT}$  and  $V_{LDO}$  should be  $\pm 500\text{mV}$ .

## Applications Information (continued)

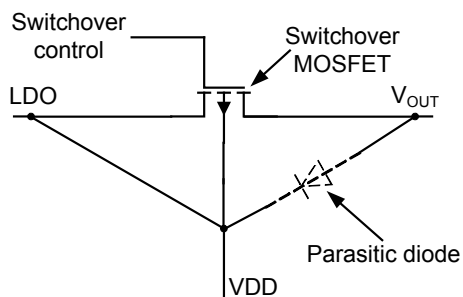
In many applications, the EN/PSV pin will be pulled high to the VDD node to allow control of the PWM and LDO ENL pin. If the switch over feature is used, this circuit must be implemented with caution or the circuit may be damaged. In the case where the ENL pin is being controlled by a GPIO signal or is tied directly to the input voltage, the ENL pin can be pulled low while the PWM is still generating an output voltage that is seen across one of the switch-over diodes. This may result in the VDD node being held above its UVLO threshold while the LDO is deactivated. Operating in this way can potentially damage the part.

In the case where the ENL pin is used to control the input UVLO, it is acceptable to connect EN/PSV directly to the VDD node.

It is not recommended to use the switch-over feature for an output voltage less than 3V since this does not provide sufficient voltage for the gate-source drive to the internal p-channel switch-over MOSFET.

### Switch-over MOSFET Parasitic Diode

The switch-over MOSFET contains a parasitic diode that is inherent to its construction, as shown in Figure 12.



**Figure 12— Switch-over MOSFET Parasitic Diodes**

If  $V_{OUT}$  is higher than VDD, then the diode will turn on and the SC403 operating current will flow through this diode. This has the potential of damaging the device.

There are some important design rules that must be followed to prevent forward bias of this diode. The following condition,  $V_{DD} \geq V_{OUT}$  needs to be satisfied in order for the parasitic diode to stay off and prevent damaging the device. Many applications connect the EN pin to V5V and control the on/off of the LDO and PWM simultaneously with the ENL pin. This allows one signal to control both

the bias and power output of the SC403. When  $V_{OUT} > 3.0V$  this configuration can cause problems due to the parasitic diodes in the LDO switchover circuitry. After the  $V_{OUT} > 3.0V$  PWM output is up and running the switchover diodes can hold up  $V5V > UVLO$  even if the ENL pin is grounded, turning off the LDO. Operating in this way can potentially damage the part.

### Design Procedure

When designing a switch mode supply the input voltage range, load current, switching frequency, and inductor ripple current must be specified.

The maximum input voltage ( $V_{INMAX}$ ) is the highest specified input voltage. The minimum input voltage ( $V_{INMIN}$ ) is determined by the lowest input voltage after evaluating the voltage drops due to connectors, fuses, switches, and PCB traces.

The following parameters define the design.

- Nominal output voltage ( $V_{OUT}$ )
- Static or DC output tolerance
- Transient response
- Maximum load current ( $I_{OUT}$ )

There are two values of load current to evaluate — continuous load current and peak load current. Continuous load current relates to thermal stresses which drive the selection of the inductor and input capacitors. Peak load current determines instantaneous component stresses and filtering requirements such as inductor saturation, output capacitors, and design of the current limit circuit.

The following values are used in this design.

- $V_{IN} = 12V \pm 10\%$
- $V_{OUT} = 1.5V \pm 4\%$
- $f_{SW} = 300kHz$
- Load = 6A maximum

### Frequency Selection

Selection of the switching frequency requires making a trade-off between the size and cost of the external filter components (inductor and output capacitor) and the power conversion efficiency.

## Applications Information (continued)

The desired switching frequency is 300kHz which results from using components selected for optimum size and cost.

A resistor ( $R_{TON}$ ) is used to program the on-time (indirectly setting the frequency) using the following equation.

$$R_{TON} = \frac{(t_{ON} - 10ns) \times V_{IN}}{25pF \times V_{OUT}}$$

To select  $R_{TON}$ , use the maximum value for  $V_{IN}$  and for  $t_{ON}$  use the value associated with maximum  $V_{IN}$ .

$$t_{ON} = \frac{V_{OUT}}{V_{INMAX} \times f_{SW}}$$

$$t_{ON} = 379 \text{ ns at } 13.2V_{IN}, 1.5V_{OUT}, 300kHz$$

Substituting for  $R_{TON}$  results in the following solution.

$$R_{TON} = 129.9k\Omega, \text{ use } R_{TON} = 130k\Omega$$

### Inductor Selection

In order to determine the inductance, the ripple current must first be defined. Low inductor values result in smaller size but create higher ripple current which can reduce efficiency. Higher inductor values will reduce the ripple current and ripple voltage and for a given DC resistance are more efficient. However, larger inductance translates directly into larger packages and higher cost. Cost, size, output ripple, and efficiency are all used in the selection process.

The ripple current will also set the boundary for PSAVE operation. The switching will typically enter PSAVE mode when the load current decreases to 1/2 of the ripple current. For example, if ripple current is 4A then PSAVE operation will typically start for loads less than 2A. If ripple current is set at 40% of maximum load current, then PSAVE will start for loads less than 20% of maximum current.

The inductor value is typically selected to provide a ripple current that is between 25% to 50% of the maximum load current. This provides an optimal trade-off between cost, efficiency, and transient performance.

During the DH on-time, voltage across the inductor is  $(V_{IN} - V_{OUT})$ . The equation for determining inductance is shown next.

$$L = \frac{(V_{IN} - V_{OUT}) \times t_{ON}}{I_{RIPPLE}}$$

### Example

In this example, the inductor ripple current is set equal to 50% of the maximum load current. Therefore ripple current will be 50% x 6A or 3A. To find the minimum inductance needed, use the  $V_{IN}$  and  $t_{ON}$  values that correspond to  $V_{INMAX}$ .

$$L = \frac{(13.2 - 1.5) \times 379ns}{3A} = 1.48\mu H$$

A slightly larger value of 1.5 $\mu$ H is selected. This will decrease the typical  $I_{RIPPLE}$  to 2.7A.

Note that the inductor must be rated for the maximum DC load current plus 1/2 of the ripple current.

The ripple current under minimum  $V_{IN}$  conditions is also checked using the following equations.

$$t_{ON\_VINMIN} = \frac{25pF \times R_{TON} \times V_{OUT}}{V_{INMIN}} + 10ns = 461ns$$

$$I_{RIPPLE} = \frac{(V_{IN} - V_{OUT}) \times t_{ON}}{L}$$

$$I_{RIPPLE\_MIN} = \frac{(10.8 - 1.5) \times 461ns}{1.5\mu H \times (1 + 0.2)} = 2.38A$$

$$I_{RIPPLE\_MAX} = \frac{(10.8 - 1.5) \times 379ns}{1.5\mu H \times (1 - 0.2)} = 3.7A$$

The value of L has been adjusted by  $\pm 20\%$  for the equations above assuming an inductor tolerance of  $\pm 20\%$ .

### Output Capacitor Selection

The output capacitors are chosen based upon required ESR and capacitance. The maximum ESR requirement is controlled by the output ripple requirement and the DC tolerance. The output voltage has a DC value that is equal to the valley of the output ripple plus 1/2 of the peak-to-peak ripple. A change in the output ripple voltage will lead to a change in DC voltage at the output.



## Applications Information (continued)

The design goal is that the output voltage regulation be  $\pm 4\%$  under static conditions. The internal 750mV reference tolerance is  $\pm 1\%$ . Allowing  $\pm 1\%$  tolerance from the FB resistor divider, this allows 2% tolerance due to  $V_{OUT}$  ripple. Since this 2% error comes from 1/2 of the ripple voltage, the allowable ripple is 4%, or 60mV for a 1.5V output.

The maximum ripple current of 3.7A creates a ripple voltage across the ESR. The maximum ESR value allowed is shown by the following equations.

$$ESR_{MAX} = \frac{V_{RIPPLE}}{I_{RIPPLEMAX}} = \frac{60mV}{3.7A}$$

$$ESR_{MAX} = 16.2 \text{ m}\Omega$$

The output capacitance is usually chosen to meet transient requirements. A worst-case load release, from maximum load to no load at the exact moment when the inductor current is at the peak, determines the required capacitance. If the load release is instantaneous (load changes from maximum to zero in  $< 1\mu s$ ), the output capacitor must absorb all the inductor's stored energy. This will cause a peak voltage on the capacitor requiring a capacitance provided by the following equation.

$$C_{OUT_{MIN}} = \frac{L \left( I_{OUT} + \frac{1}{2} \times I_{RIPPLEMAX} \right)^2}{(V_{PEAK})^2 - (V_{OUT})^2}$$

Assuming a peak voltage  $V_{PEAK}$  of 1.6V (100mV rise upon load release), and a 6A load release, the required capacitance is shown by the next equation.

$$C_{OUT_{MIN}} = \frac{1.5\mu H \left( 6A + \frac{1}{2} \times 3.7A \right)^2}{(1.6V)^2 - (1.5V)^2}$$

$$C_{OUT_{MIN}} = 298\mu F$$

If the load release is relatively slow, the output capacitance can be reduced. At heavy loads during normal switching, when the FB pin is above the 750mV reference, the DL output is high and the low-side MOSFET is on. During this time, the voltage across the inductor is approximately  $-V_{OUT}$ . This causes a down-slope or falling  $di/dt$  in the

inductor. If the load  $di/dt$  is not much faster than the  $-di/dt$  in the inductor, then the inductor current will tend to track the falling load current. This will reduce the excess inductive energy that must be absorbed by the output capacitor, therefore a smaller capacitance can be used.

The following can be used to calculate the needed capacitance for a given  $di_{LOAD}/dt$ .

Peak inductor current is shown by the next equation.

$$I_{L_{PK}} = I_{MAX} + 1/2 \times I_{RIPPLEMAX}$$

$$I_{L_{PK}} = 6 + 1/2 \times 3.7 = 7.9A$$

$$\text{Rate of change of Load Current} = \frac{di_{LOAD}}{dt}$$

$$I_{MAX} = \text{maximum load release} = 6A$$

$$C_{OUT} = I_{L_{PK}} \times \frac{L \times \frac{I_{L_{PK}}}{V_{OUT}} - \frac{I_{MAX}}{di_{LOAD}} \times dt}{2(V_{PK} - V_{OUT})}$$

### Example

$$\frac{di_{LOAD}}{dt} = \frac{2A}{1\mu s}$$

This would cause the output current to move from 6A to 0A in  $3.0\mu s$ , giving the minimum output capacitance requirement shown in the following equation.

$$C_{OUT} = 7.9A \times \frac{1.5\mu H \times \frac{7.9}{1.5} - \frac{6}{2} \times 1\mu s}{2(1.6V - 1.5V)}$$

$$C_{OUT} = 194 \mu F$$

Note that  $C_{OUT}$  is much smaller in this example, 194 $\mu F$  compared to 298 $\mu F$  based on a worst-case load release. To meet the maximum design criteria of minimum 298 $\mu F$  and maximum 16m $\Omega$  ESR, select one capacitor rated at 330 $\mu F$  and 9m $\Omega$  ESR.

It is recommended that an additional small capacitor be placed in parallel with  $C_{OUT}$  in order to filter high frequency switching noise.

## Applications Information (continued)

### Soft Start Capacitor Selection

For a soft-start time ( $t_{SS}$ ) of approximately 3ms, solve the following equation for  $C_{SS}$ .

$$C_{SS} = t_{SS} \frac{2.75\mu A}{1.5V}$$

$$C_{SS} = 5.5nF$$

If  $C_{SS}$  is selected as 4.7 nF, then  $t_{SS}$  will be 2.6 ms.

Then the PGOOD delay, the time from  $V_{OUT}$  regulation to PGOOD signal high is shown by the following equation.

$$t_{PGOOD-DELAY} = \frac{4.7nF \times (0.64V_{DD} - 1.5V)}{2.75\mu A}$$

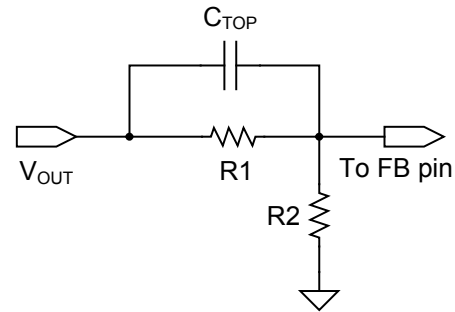
At  $V_{DD} = 5V$ , the PGOOD delay will be 2.9ms.

### Stability Considerations

Unstable operation is possible with adaptive on-time controllers, and usually takes the form of double-pulsing or ESR loop instability.

Double-pulsing occurs due to switching noise seen at the FB input or because the FB ripple voltage is too low. This causes the FB comparator to trigger prematurely after the 250ns minimum off-time has expired. In extreme cases the noise can cause three or more successive on-times. Double-pulsing will result in higher ripple voltage at the output, but in most applications it will not affect operation. This form of instability can usually be avoided by providing the FB pin with a smooth, clean ripple signal that is at least 10mVp-p, which may dictate the need to increase the ESR of the output capacitors. It is also imperative to provide a proper PCB layout as discussed in the Layout Guidelines section.

Another way to eliminate doubling-pulsing is to add a small (~ 10pF) capacitor across the upper feedback resistor, as shown in Figure 13. This capacitor should be left unpopulated until it can be confirmed that double-pulsing exists. Adding the  $C_{TOP}$  capacitor will couple more ripple into FB to help eliminate the problem. An optional connection on the PCB should be available for this capacitor.



**Figure 13 — Capacitor Coupling to FB Pin**

ESR loop instability is caused by insufficient ESR. The details of this stability issue are discussed in the ESR Requirements section. The best method for checking stability is to apply a zero-to-full load transient and observe the output voltage ripple envelope for overshoot and ringing. Ringing for more than one switching cycle after the initial step is an indication that the ESR should be increased.

One simple way to solve this problem is to add trace resistance in the high current output path. A side effect of adding trace resistance is a decrease in load regulation performance.

### ESR Requirements

A minimum ESR is required for two reasons. One reason is to generate enough output ripple voltage to provide 10mVp-p at the FB pin (after the resistor divider) to avoid double-pulsing.

The second reason is to prevent instability due to insufficient ESR. The on-time control regulates the valley of the output ripple voltage. This ripple voltage is the sum of the two voltages. One is the ripple generated by the ESR, the other is the ripple due to capacitive charging and discharging during the switching cycle. For most applications the minimum ESR ripple voltage is dominated by the output capacitors, typically SP or POSCAP devices. For stability the ESR zero of the output capacitor should be lower than approximately one-third the switching frequency. The formula for minimum ESR is shown by the following equation.